

GK7205V210 Datasheet

Version 1.1

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Version History

Version	Note
V0.1	Initial Version
V0.2	Format Adjustment
V0.3	Add Order Notes
V1.1	Additional hardware features



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1.Overview

The GK7205V210 chip is a new generation of low-power multimedia SOC chip that supports H.265 encoding from GOK.

The chip integrates a dedicated ISP with efficient video encoding processing performance and supports H.265 encoding to meet customers' various differentiated business needs. The integrated RTC, POR, Audio codec and rich peripheral interfaces help customers to reduce BOM cost, and the low-power CPU and low-power architecture help customers to reduce power consumption.

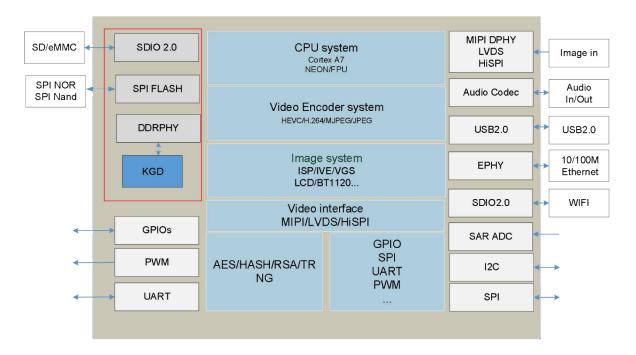


Figure 0-1: GK7205V210 Function Block Diagram



2. Key Features

CPU

- ARM Cortex A7 @ 900MHz
- 32KB I-Cache, 32KB D-Cache, 128KB L2
 Cache
- Integrated multimedia acceleration engine -NEON and hardware Java acceleration
- Integrated hardware floating point co-processor

Storage interface and startup

- Embedded 512Mb DDR2
- Supports up to 1200Mbps
- Support SPI Nor Flash, maximum capacity 256MB
- Supports SPI Nand Flash with a maximum capacity of 1GB
- Supports eMMC 4.5, up to 2TB capacity
- Selectable boot from SPI Nor or SPI Nand or eMMC

Video Encoding

- Support H.265/H.264 video encoding
 - ✓ Supports a maximum resolution of 2560x1440
- MJPEG/JPEG encoding support
- Support
 CBR/VBR/FIXQP/AVBR/QPMAP/CVBR

Audio Codec

Support software codec, support G.711G.726,

ADPCM

Support Audio 3A (AEC/ANR/AGC)

Video and graphics processing

Support for multiple application analysis



- Support video, graphics PQ boost
- Support ISP

Safe handling

- Supports AES/RSA and other algorithms
- HASH Support
- OTP support
- Support TRNG

Audio and video interface

- Video Input
 - ✓ Supports MIPI, LVDS, HiSPI interfaces
 - ✓ Support various mainstream HD sensors
- Video Output
 - ✓ LCD output support
 - ✓ Supports BT656/BT1120 output
- Audio Interface
 - ✓ Supports mic/line in input
 - ✓ Support line out output
 - ✓ I2S support

Peripherals & Others

- Supports one USB2.0 Host/Device interface
- Supports one SDIO2.0 with SD2.0 card
- Supports 10M/100M Ethernet with built-in EPHY
- Supports four PWMs
- Supports three UART interfaces



- Dual-channel SAR ADC support
- Multiple I2C interfaces; multiple GPIO interfaces
- SPI interface support
- Built-in high-precision RTC

Physical Specifications

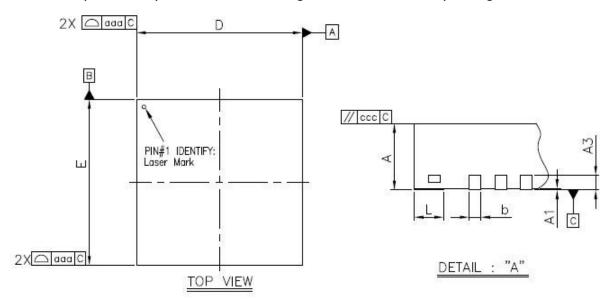
- Operating Voltage
 - ✓ Core Voltage: 0.9v
 - ✓ IO Voltage: 3.3v
 - ✓ SDRAM Voltage: 1.8v
- Package:
 - ✓ QFN 9mm * 9mm, 88pins



3. Package and Pinouts

3.1 Package

GK7205V210 chip adopts QFN package, the package size is 9mm×9mm, the pin pitch is 0.35mm, the total number of pins is 88, please refer to the figure for the detailed package.



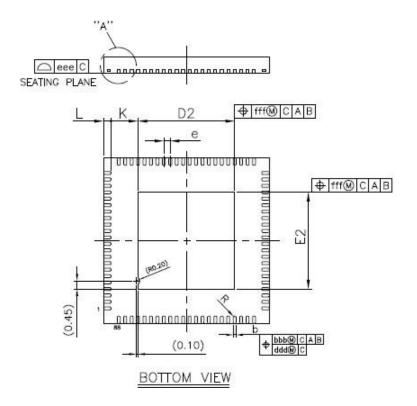


Figure 3-1 GK7205V210 chip package diagram



Table 3-1 GK7205V210 chip package parameters

6 1 1	Dimen	sion in	mm	Dimer	nsion in	inch		
Symbol	MIN	NOM	MAX	MIN	NOM	MAX		
Α	0.85	0.90	0.95	0.033	0.035	0.037		
A1	0.00	0.02	0.05	0.000	0.001	0.002		
А3	(0.20 REF	100	(0.008 REF			
b	0.11	0.16	0.21	0.004	0.006	0.008		
D	8.90	9.00	9.10	0.350	0.354	0.358		
Е	8.90	9.00	9.10	0.350	0.354	0.358		
D2	5.16	5.26	5.36	0.203	0.207	0.211		
E2	5.16	5.26	5.36	0.203	0.207	0.211		
е	().35 BSC		0.014 BSC				
L	0.30	0.40	0.50	0.012	0.016	0.020		
K	0.20	entro entro entro		0.008	0.000.00000.00000	10 -10-1-1 8		
R	0.055		0.105	0.002		0.004		
aaa	Co.	0.10		0.004				
ddd	No.	0.07		0.003				
ccc	No.	0.10		0.004				
ddd	No.	0.05		0.002				
eee		0.08	4	0.003				
fff	V _c	0.10		0.004				

NOTE:

- 1. CONTROLLING DIMENSION: MILLIMETER
- 2. REFERENCE DOCUMENT: JEDEC MO-220.



3.2 Pin Distribution

	88	87	86	85	84	83	82	81	80	79	78	77	76	75	74	73	72	71	70	69	68	67		
PIN 1	CSADC_CHO	LSADC_CH1	JTAG_TDO	JTAG_TDI	DVDD33	JTAG_TMS	JTAG_TCK	JTAG_TRSTN	WDD	VSS	VDDIO_DDR	VDD	AVDD33_DDR_PLI	VDDIO_DDR	UARTO_RXD	UARTO_TXD	0_00I9	TWM-I	OWMA	SYS_RSTW_OUT	SFC_MOSI_IOO	NTO_ORS		
1 AVDD_BAT	8																						SFC_HOLD_IO3	66
2 RTC_XIN																							SFC_CSN	65
3 RTC_XOUT																							SFC_MISO_IO1	64
4 AVDD33_PLL																							SFC_WP_IO2	63
5 AVDD_PLL																							VDD	62
6 XIN																							SDIOO_CARD_DETECT	T61
7 XOUT																							SDIOO_CDATA1	60
8 DVDD33																							DVDD3318_FLASH	59
9 LCD_DATAO																							SDIOO_CDATAO	58
10 LCD_DATA1																_		_					SDIOO_CCLK_OUT	57
11 LCD_DATA2			1	1	L	7	7		7	1						2) -	1					SDIOO_CCMD	56
12 LCD_DATA3			ı	T	r		1		/,	I	J			V		/			1	,			SDIOO_CDATA3	55
13 VDD						•									•		3			1			SDIOO_CDATA2	54
14 LCD_DATA4																							VDD	53
15 LCD_DATA5																							USB_DM	52
16 LCD_DATA6																							USB_DP	51
17 DVDD3318_VIVO																							AVDD33_AC_U2	50
18 LCD_DATA7																							AC_OUTL	49
19 LCD_CLK																							AC_MICBIAS	48
20 LCD_HS																							AC_INL	47
21 LCD_VS																							AC_VREF	46
22 LCD_DE																							AVSS_AC	45
	NE_IOM_HTH 33	AR I OW I HLE 24	S AVDD33_FE	S ETH_MDI_AN	TH_MOI_AP	S ETH_LINK_ACT_LE	S ETH_LINK_STA_LE	S I2C2_SCL	TCC2_SDA	S DVDD3318_SENSOR	S I2CO_SDA	12CO_SCL	SENSOR_CLK	S SENSOR_RSTW	37	S AVDD3318_MIPIRX	% MIPI_RX_CKOP	#IPI_RX_CKON	MIPI_RX_DOP	MIPI_RX_DON	MIPI_RX_D2P	A MIPI_RX_D2W		
								-	-	-	-0	5.5	~~	~~			~~	•~	(3/5)	•		9.5		

Figure 3-2 GK7205V210 pinout diagram



4. Hardware Features

4.1 Welding process recommendations

4.1.1 Lead-free reflow soldering process parameters requirements

The lead-free reflow soldering process profile is shown in Figure 4-1.

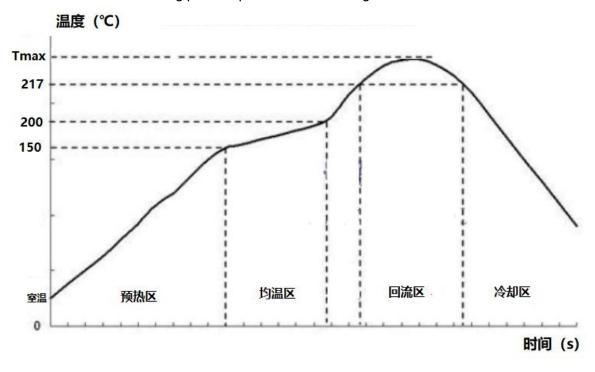


Figure 4-1. Lead-free reflow soldering process curve

Welding area	Time	Heating rate	Peak temperature	Cooling rate
Preheating zone (room temperature ~ 150°C)	60 to 150s	≤2.0°C/s	-	-
Homogeneous temperature zone (150~200°C)	60 to 120s	<1.0°C/s	-	-
Reflux zone (>217°C)	60 to 90s	-	Tmax=230-260°C	-



Cooling zone (Tmax ~	-	-	-	1.0°C/s≤Slope≤4.0°C/s
180°C)				



Table 4-1 Lead-free reflow soldering process parameters

Lead-free reflow soldering process parameters are described:

Preheating zone: temperature from room temperature to 150 $^{\circ}$ C, the temperature rise rate is controlled at about 2 $^{\circ}$ C / s, the temperature zone time is 60 $^{\sim}$ 150s.

Even temperature zone: temperature from $150 \,^{\circ}\text{C} \sim 200 \,^{\circ}\text{C}$, stable and slow heating, the temperature rise rate is less than $1 \,^{\circ}\text{C} / \text{s}$, and the region time control in $60 \,^{\sim} \, 120 \, \text{s}$ (Note: the region must be slowly heated, otherwise it is easy to lead to poor welding).

Reflow zone: temperature from $217^{\circ}\text{C} \sim \text{Tmax} \sim 217^{\circ}\text{C}$, the whole zone time control in $60\sim 90\text{s}$. $60\sim 90\text{s}$ as the target of reflow time, for some heat capacity can not meet the time requirements of the veneer can be relaxed to 120s reflow time.

Cooling zone: temperature from Tmax to 180°C, the maximum temperature drop rate should not exceed 4°C/s. The total time for temperature rise from room temperature to Tmax should not exceed 6 minutes.

The reflow curve is only the recommended value, the client needs to make corresponding adjustments according to the actual production situation

4.2 Tide sensitive parameters

This section sets out the principles for the use of ICs (tide sensitive products) and covers the following explanation of terms:

- Floor life: the maximum time the product is allowed to remain in the workshop (ambient <30°C/60% RH, before unpacking the moisture-proof package to reflow)
- Desiccant (desiccant): a material used to adsorb moisture and keep it dry
- Humidity Indicator Card (HIC): Humidity Indicator Card
- Moisture sensitivity level (MSL): Moisture sensitivity level
- Moisture Barrier Bag (MBB): Moisture Barrier Bag
- Solder Reflow: Reflow soldering
- Shelf Life: normal storage time after moisture-proof packaging

Tide Sensitive Grade

The moisture sensitivity level of this product is 3.

4.2.1 Product moisture-proof packaging

4.2.1.1 Packaging Information

Dry vacuum packaging materials contain:



- Humidity Indicator Card (HIC)
- Moisture Barrier Bag (MBB)
- Desiccant



DAWGER PAUME

LEVEL 3

1. SHELF LIFE IN SEALED BAG IZ MONTHS AT 30 CANDGO'S REATHY EMMORTING AND TO THAT WILL BE SUBJECTED TO INFRACED REPLOW NAVAR-PHASE REPLOW, REQUIRATING PROCESSING MUST BE. MOUNTED WITHIN TOANS (168 HES) AT PACTORY PONDITION OF 30 DOY 60 No. 10 A PACTORY PONDITION OF 30 DOY 60 No. 10 A PACTORY PONDITION OF 30 DOY 60 No. 10 A PACTORY PONDITION OF 30 DOY 60 No. 10 A PACTORY PONDITION OF 30 DOY 60 No. 10 A PACTORY PONDITION OF 30 DOY 60 No. 10 A PACTORY PONDITION OF 30 DOY 60 No. 10 A PACTORY PONDITION OF 30 DOY 60 No. 10 A PACTORY PONDITION OF 30 DOY 60 No. 10 A PACTORY PONDITION OF 30 DOY 60 No. 10 A PACTORY PONDITION OF 30 DOY 60 No. 10 A PACTORY PONDITION OF 30 DOY 60 No. 10 A PACTORY PONDITION OF 30 DOY 60 No. 10 A PACTORY PONDITION OF 30 DOY 60 No. 10 A PACTORY PONDITION OF 30 DOY 60 No. 10 A PACTORY PONDITION OF 30 DOY 60 No. 10 A PACTORY PONDITION OF 30 DOY 60 NO. 10 A PACTORY PONDITIO

Figure 4-2 Schematic diagram of dry vacuum packaging materials

4.2.1.2 Tide sensitive products incoming inspection

Prior to production use (SMT), after opening the vacuum bag:

- If the maximum indication point of the HIC has changed (not blue or earthen), the product must be rebake with reference to Table 4-3.
- If the 10% RH dot in the HIC is blue or earthy, the product is dry and can be vacuum sealed by simply replacing the moisture barrier.

4.2.2 Storage and Use

[Storage Environment

It is recommended to store the product in vacuum packaging at <30°C/60% RH.

[shelf life] (normal storage time after moisture-proof packaging)

Storage environment <30°C/60% RH, vacuum packaging storage, shelf life (storage period) of not less than 12 months.

(floor life

At ambient conditions <30°C/60%, floor life is referenced below.

Table 4-2 Floor life reference table

MSL	Floor life(out of bag) at factory ambient≦30°C/60% RH or as stated
1	Unlimited at ≦30°C/85% RH



2	1 year
1	,



MSL	Floor life(out of bag) at factory ambient≦30°C/60% RH or as stated
2a	4 weeks
3	168 hours
4	72 hours
5	48 hours
5a	24 hours
6	Mandatory bake before use, must be reflowed within the time limit specified on the label

The use of [Chao Min products].

- If the product is exposed to ≦30°C/60%RH for more than 2 hours continuously or cumulatively, it is recommended to rebake and then vacuum dry the package.
- If the product is exposed under ≦30°C/60%RH for not more than 2 hours in total, it can be used without rebake, but it should be replaced with new desiccant and vacuum dried and packed.

For storage and usage principles not mentioned in this document, please refer directly to JEDEC J-STD-033A.

4.2.3 Re-baking

[Scope of Use

ICs that need to be re-baked (moisture sensitive products)

[Re-baking reference table]

Table 4-3 Re-baking reference table

Body thickness	level	bake@125°C	bake@90°C≦5% RH	bake@40°C≦5% RH
≦1.4mm	2a	3 hours	11 hours	5 days
	3	7hours	23 hours	9 days
	4	7 hours	23 hours	9 days
	5	7 hours	24 hours	10 days
	5a	10 hours	24 hours	10 days
≦2.0mm	2a	16 hours	2 days	22 days
	3	17 hours	2 days	23 days
	4	20 hours	3 days	28 days
	5	25 hours	4 days	35 days
	5a	40 hours	6 days	56 days
≦4.5mm	2a	48 hours	7 days	67 days





Body thickness	level	bake@125°C	bake@90°C≦5% RH	bake@40°C≦5% RH				
	3	48 hours	8 days	67 days				
	4	48 hours	10 days	67 days				
	5	48 hours	10 days	67 days				
	5a	48 hours	10 days	67 ays				
Remarks	low tempe	This table shows the minimum baking time necessary after moisture. Re-baking preference is given to low temperature baking. Please refer to JEDEC for details						



5. Electrical performance

5.1 Extreme working conditions

Permanent damage may occur if the chip is operated at maximum rated conditions beyond the limit operating conditions. Functional operation should be limited to the conditions given in the "Recommended Operating Conditions" section. Prolonged operation under extreme operating conditions may affect the reliability of the device. Chip junction temperatures exceeding destructive junction temperatures may result in physical damage to the chip.

Parameters Symbols Unit Sco pe 0V9 -0.2 to +1.171V8 Supply voltage -0.2 to +2.16٧ 3V3 -0.2 to +3.96125 $^{\circ}$ C Destructive junction temperature

Table 5-1 Limiting operating conditions (VSS=0V)

5.2 Recommended working conditions

Table 5-2 Recommended working conditions

Parameters	Symbols			Unit	
		Minimum	Typical	Maximum	
		value	values	value	
	0V9	TBD	0.9	TBD	
Supply Voltage	1V8	TBD	1.8	1.89	V
	3V3	3.135	3.3	3.465	
Chip ambient	TA	0	_	70	°C
temperature					
Chip junction	TJ	0	_	105	°C
temperature					



5.3 DC gas parameters

		Conditions	Minimu m value	Typical values	Maximu m value	Unit
High level output	VOH		2.4	_	_	
voltage		0voltage = 3.3V				V
Low level output	VOL		_	_	0.4	
voltage						
High level input	VIH		2	_	_	
voltage						



Low level input voltage	VIL		-	-	0.8	
High level output voltage	VOH	10.11	1.35	-	-	
Low level output voltage	VOL	0voltage = 1.8V	-	_	0_4	
High level input voltage	VIH		1.27	-	-	
Low level input voltage	VIL		-	-	0.58	

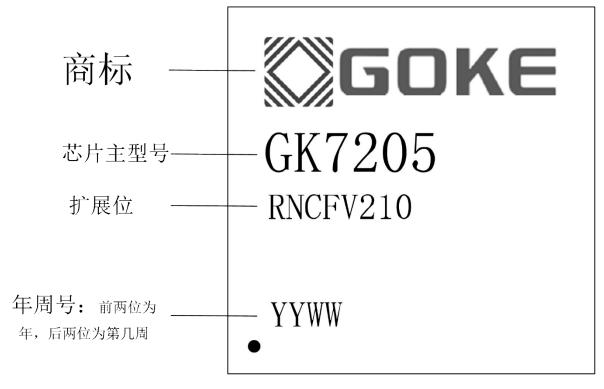
Table 5- 3 DC Electrical Parameters



6. Ordering Information

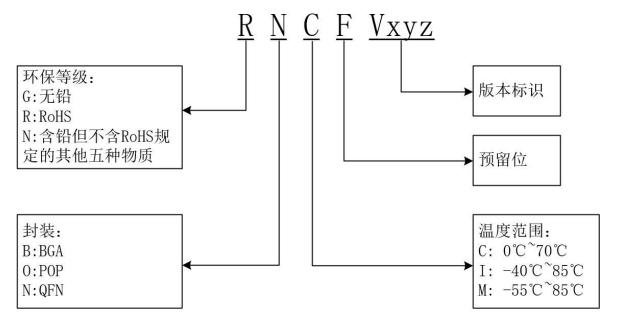
Chip identification and definition

Chip identification:





Extended bit definition:





7.RoHS Description

All GK7205V210 products provided to our customers are RoHS products, i.e., they are Lead-free.